

# R1LP0408D Series

4Mb Advanced LPSRAM (512-kword × 8-bit)

R10DS0104EJ0200 Rev.2.00 2012.5.30

### **Description**

The R1LP0408D Series is a family of 4-Mbit static RAMs organized 512-kword × 8-bit, fabricated by Renesas's high-performance CMOS and TFT technologies. The R1LP0408D Series has realized higher density, higher performance and low power consumption. The R1LP0408D Series offers low power standby power dissipation; therefore, it is suitable for battery backup systems. It is offered in 32-pin SOP and 32-pin TSOP.

#### **Features**

Single 5V supply: 4.5V to 5.5VAccess time: 55/70ns (max)

Power dissipation:

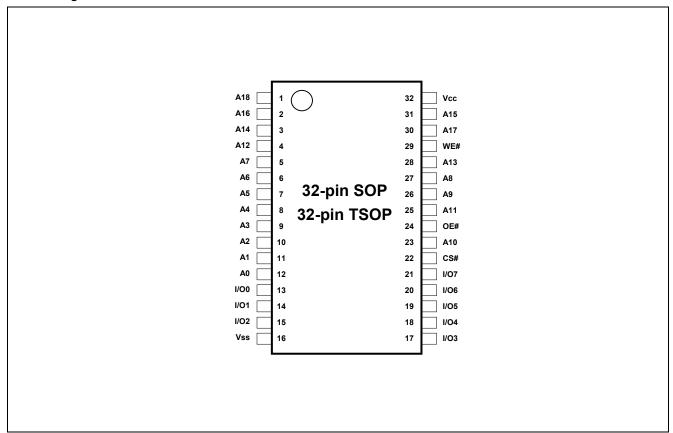
 Standby: 4μW (typ)

- Equal access and cycle times
- Common data input and output
- Three state outputDirectly TTL compatible
  - All inputs and outputs
- Battery backup operation

### **Part Name Information**

Part Name	Access time	Temperature Range	Package	Shipping Container	Quantity
R1LP0408DSP-5SR#B*	55 ns	0 ~ +70°C			
R1LP0408DSP-5SI#B*	33 118	-40 ~ +85°C		Tube	Max. 25pcs/Tube
R1LP0408DSP-7SR#B*	70 ns	0 ~ +70°C	525-mil 32-pin	Tube	Max. 225pcs/Inner Bag Max. 900pcs/Inner Box
R1LP0408DSP-7SI#B*	70 ns	-40 ~ +85°C	plastic SOP		·
R1LP0408DSP-5SR#S*	55 ns	0 ~ +70°C	PRSP0032DF-A		
R1LP0408DSP-5SI#S*	33 118	-40 ~ +85°C	(032P2S-A)	Embossed	1000nos/Pool
R1LP0408DSP-7SR#S*	70 ns	0 ~ +70°C		tape	1000pcs/Reel
R1LP0408DSP-7SI#S*	70118	-40 ~ +85°C			
R1LP0408DSB-5SR#B*	55 ns	0 ~ +70°C			
R1LP0408DSB-5SI#B*	33 118	-40 ~ +85°C		Trov	Max. 117pcs/Tray
R1LP0408DSB-7SR#B*	70 ns	0 ~ +70°C	400-mil 32-pin	Tray	Max. 936pcs/Inner Box
R1LP0408DSB-7SI#B*	70118	-40 ~ +85°C	plastic TSOP(II)		
R1LP0408DSB-5SR#S*	55 ns	0 ~ +70°C	PTSB0032DC-A		
R1LP0408DSB-5SI#S*	30 118	-40 ~ +85°C	(032PTY-A)	Embossed	1000non/Pool
R1LP0408DSB-7SR#S*	70 ns	0 ~ +70°C		tape	1000pcs/Reel
R1LP0408DSB-7SI#S*	70118	-40 ~ +85°C			

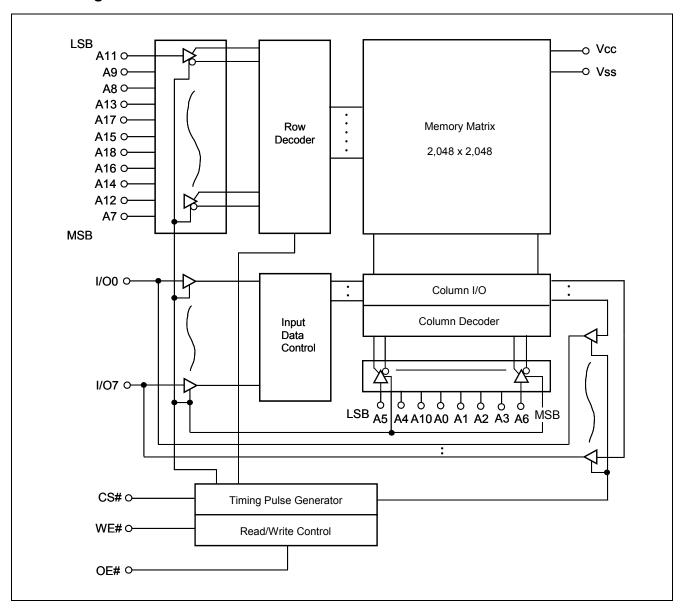
#### Pin Arrangement



# **Pin Description**

Pin name	Function	
Vcc	Power supply	
Vss	Ground	
A0 to A18	Address input	
I/O0 to I/O7	Data input/output	
CS#	Chip select	
WE#	Write enable	
OE#	Output enable	

## **Block Diagram**



# **Operation Table**

WE#	CS#	OE#	Mode	Vcc current	I/O0 to I/O7	Ref. cycle
×	Н	×	Not selected	I <sub>SB</sub> , I <sub>SB1</sub>	High-Z	_
Н	L	Н	Output disable	lcc	High-Z	_
Н	L	L	Read	Icc	Dout	Read cycle
L	L	Н	Write	Icc	Din	Write cycle (1)
L	L	L	Write	lcc	Din	Write cycle (2)

Note 1. H: V<sub>IH</sub> L:V<sub>IL</sub> ×: V<sub>IH</sub> or V<sub>IL</sub>

## **Absolute Maximum Ratings**

Parameter	Symbol	Va	lue	unit
Power supply voltage relative to Vss	Vcc	-0.5 to	-0.5 to +7.0	
Terminal voltage on any pin relative to Vss	V <sub>T</sub>	-0.5 <sup>*1</sup> to \	Vcc+0.3 <sup>*2</sup>	V
Power dissipation	P <sub>T</sub>	0	.7	W
Operation temperature	Topr*3	R Ver.	0 to +70	°C
Operation temperature	Торг	I Ver.	-40 to +85	C
Storage temperature range	Tstg	-65 to	o 150	°C
Storage temperature range under him	Tbias*3	R Ver.	0 to +70	°C
Storage temperature range under bias	Iblas	I Ver.	-40 to +85	C

Note 1. -3.0V for pulse  $\leq 30$ ns (full width at half maximum)

- 2. Maximum voltage is +7.0V.
- 3. Ambient temperature range depends on R/I-version. Please see table on page 1.

### **DC Operating Conditions**

Parameter		Symbol	Min.	Тур.	Max.	Unit	Note
Supply voltage		Vcc	4.5	5.0	5.5	V	
		Vss	0	0	0	V	
Input high voltage		$V_{IH}$	2.2	_	Vcc+0.3	V	
Input low voltage		$V_{IL}$	-0.3	_	0.8	V	1
Ambient temperature range		Та	0	_	+70	°C	2
Ambient temperature range I Ver.		ıa	-40	_	+85	°C	2

Note 1. -3.0V for pulse  $\leq 30$ ns (full width at half maximum)

2. Ambient temperature range depends on R/I-version. Please see table on page 1.

#### **DC Characteristics**

Parameter	Symbol	Min.	Тур.	Max.	Unit		Test conditions		
Input leakage current	I <sub>LI</sub>	_	_	1	μА	Vin = Vss to Vcc			
Output leakage current	I <sub>LO</sub>	_	_	1	μА	CS# =V <sub>I</sub> - VI/O =Vs	or OE# =V <sub>IH</sub> , s to Vcc		
Operating current	Icc	_	5 <sup>*1</sup>	10	mA	CS# =V <sub>IL</sub> Others =	, V <sub>IH</sub> /V <sub>IL</sub> , II/O = 0mA		
Average operating current	I <sub>CC1</sub>	_	15 <sup>*1</sup>	25	mA	1	e, duty =100%, II/O = 0mA , Others = V <sub>IH</sub> /V <sub>IL</sub>		
	I <sub>CC2</sub>	_	3 <sup>*1</sup>	5	mA	CS# ≤ 0.2	Cycle =1μs, duty =100%, II/O = 0mA CS# ≤ 0.2V, V <sub>IH</sub> ≥ Vcc-0.2V, V <sub>IL</sub> ≤ 0.2V		
Standby current	I <sub>SB</sub>	_	0.1*1	0.5	mA	CS# =V <sub>I⊢</sub>	CS# =V <sub>IH</sub> , Others = Vss to Vcc		
Standby current		_	0.8*1	2.5	μА	~+25°C			
		_	1*2	3	μА	~+40°C	Vin = Vss to Vcc,		
	I <sub>SB1</sub>	_	_	8	μА	~+70°C	CS#≥ Vcc-0.2V		
		_	_	10	μА	~+85°C			
Output high voltage	V <sub>OH</sub>	2.4	_	_	V	I <sub>OH</sub> = -1mA			
	V <sub>OH2</sub>	Vcc-0.5	_	_	V	I <sub>OH</sub> = -0.1	I <sub>OH</sub> = -0.1mA		
Output low voltage	V <sub>OL</sub>	_	_	0.4	V	I <sub>OL</sub> = 2.1mA			

Note 1. Typical parameter indicates the value for the center of distribution at 5.0V (Ta=25°C), and not 100% tested.

2. Typical parameter indicates the value for the center of distribution at 5.0V (Ta=40°C), and not 100% tested.

### Capacitance

 $(Vcc = 4.5V \sim 5.5V, f = 1MHz, Ta = 0 \sim +70^{\circ}C / -40 \sim +85^{\circ}C^{*2})$ 

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions	Note
Input capacitance	C in	_	_	8	pF	Vin =0V	1
Input / output capacitance	C <sub>I/O</sub>	_	_	10	pF	VI/O =0V	1

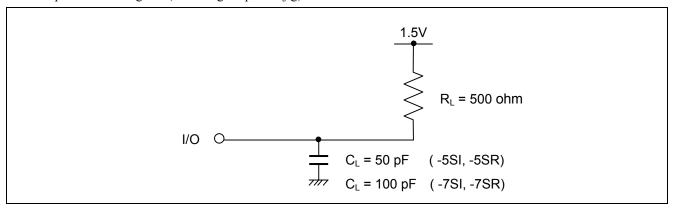
Note 1. This parameter is sampled and not 100% tested.

2. Ambient temperature range depends on R/I-version. Please see table on page 1.

### **AC Characteristics**

Test Conditions (Vcc =  $4.5V \sim 5.5V$ , Ta =  $0 \sim +70^{\circ}C / -40 \sim +85^{\circ}C^{*1}$ )

- Input pulse levels: VIL = 0.4V, VIH = 2.4V
- Input rise and fall time: 5ns
- Input and output timing reference level: 1.5V
- Output load: See figures (Including scope and jig)



Note 1. Ambient temperature range depends on R/I-version. Please see table on page 1.

#### **Read Cycle**

Parameter	Symbol	R1LP040	8DS*-5S*	R1LP040	8DS*-7S*	Unit	Note	
Faranielei	Symbol	Min.	Max.	Min.	Max.	Offic	Note	
Read cycle time	t <sub>RC</sub>	55	_	70	_	ns		
Address access time	t <sub>AA</sub>	ı	55	ı	70	ns		
Chip select access time	t <sub>ACS</sub>	ı	55	ı	70	ns		
Output enable to output valid	toE	ı	25	ı	35	ns		
Chip select to output in low-Z	t <sub>CLZ</sub>	10	_	10	_	ns	2	
Output enable to output in low-Z	t <sub>OLZ</sub>	5	_	5	_	ns	2	
Chip deselect to output in high-Z t <sub>CHZ</sub>		0	20	0	25	ns	1,2	
Output disable to output in high-Z	t <sub>OHZ</sub>	0	20	0	25	ns	1,2	
Output hold from address change t <sub>OH</sub>		10	_	10	_	ns		

#### **Write Cycle**

Note

Parameter	Symbol	R1LP040	8DS*-5S*	R1LP040	8DS*-7S*	- Unit	Note
Parameter	Symbol	Min.	Max.	Min.	Max.	Offic	Note
Write cycle time	t <sub>WC</sub>	55	_	70	_	ns	
Chip select to end of write	t <sub>CW</sub>	50	_	60	_	ns	4
Address setup time	t <sub>AS</sub>	0	_	0	_	ns	5
Address valid to end of write	t <sub>AW</sub>	50	_	60	_	ns	
Write pulse width	t <sub>WP</sub>	40	_	50	_	ns	3,12
Write recovery time	t <sub>WR</sub>	0	_	0	_	ns	6
Write to output in high-Z	t <sub>WHZ</sub>	0	20	0	25	ns	1,2,7
Data to write time overlap	t <sub>DW</sub>		_	30	_	ns	
Data hold from write time t <sub>DH</sub>		0	_	0	_	ns	
Output enable from end of write	utput enable from end of write t <sub>OW</sub>		_	5	_	ns	2
Output disable to output in high-Z $t_{OHZ}$		0	20	0	25	ns	1,2,7

- 1.  $t_{\text{CHZ}}$ ,  $t_{\text{OHZ}}$  and  $t_{\text{WHZ}}$  are defined as the time at which the outputs achieve the open circuit conditions and are not referred to output voltage levels.
- 2. This parameter is sampled and not 100% tested.
- 3. A write occurs during the overlap (twp) of a low CS# and a low WE#.

A write begins at the later transition of CS# going low or WE# going low.

A write ends at the earlier transition of CS# going high or WE# going high.

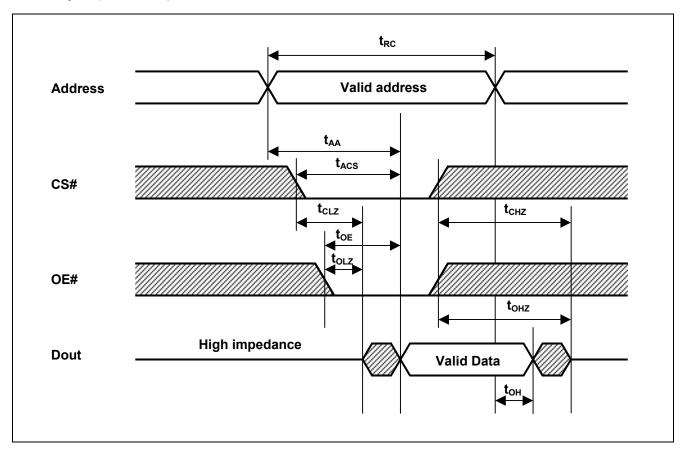
t<sub>WP</sub> is measured from the beginning of write to the end of write.

- 4. t<sub>CW</sub> is measured from CS# going low to end of write.
- 5.  $t_{AS}$  is measured the address valid to the beginning of write.
- 6. two is measured from the earlier of WE# or CS# going high to the end of write cycle.
- 7. During this period, I/O pins are in the output state so that the input signals of the opposite phase to the outputs must not be applied.
- 8. If the CS# low transition occurs simultaneously with the WE# low transition or after the WE# transition, the output remain in a high impedance state.
- 9. Dout is the same phase of the write data of this write cycle.
- 10. Dout is the read data of next address.
- 11. If CS# is low during this period, I/O pins are in the output state. Therefore, the input signals of the opposite phase to the outputs must not be applied to them.
- 12. In the write cycle with OE# low fixed, twp must satisfy the following equation to avoid a problem of data bus contention.

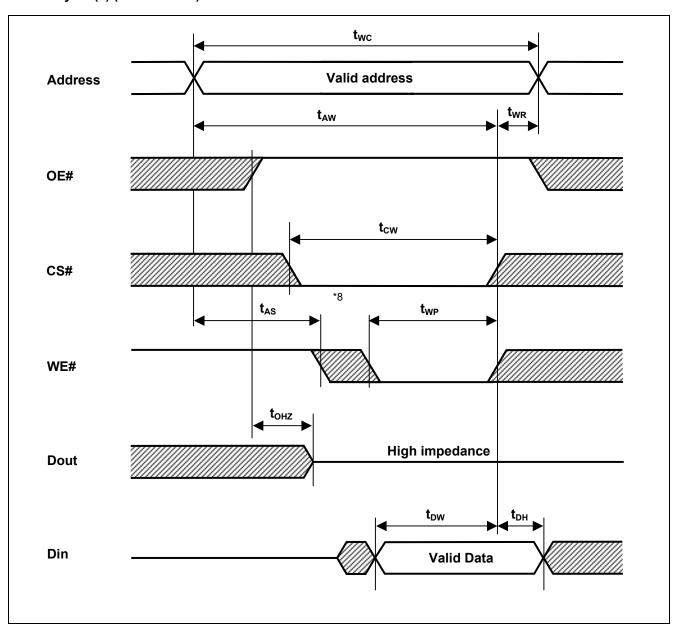
 $t_{WP} \ge t_{DW} \min + t_{WHZ} \max$ 

# **Timing Waveforms**

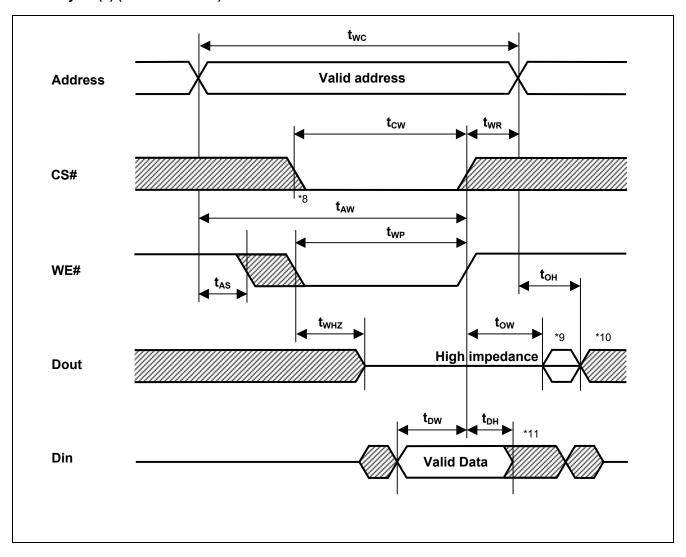
## Read Cycle (WE# = V<sub>IH</sub> )



## Write Cycle (1) (OE# CLOCK)



### Write Cycle (2) (OE# Low Fixed)



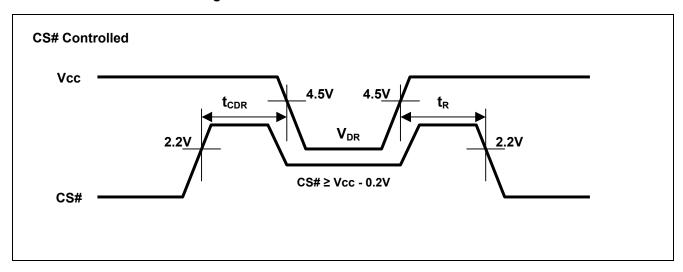
#### Low Vcc Data Retention Characteristics

Parameter	Symbol	Min.	Тур.	Max.	Unit		Test conditions*3
V <sub>CC</sub> for data retention	$V_{DR}$	2.0	_	5.5	V	Vin ≥ 0V, CS# ≥ Vcc	c-0.2V
		_	0.8*1	2.5	μА	~+25°C	
Data retantion ourrent	I <sub>CCDR</sub>	_	1 <sup>*2</sup>	3	μА	~+40°C	Vcc=3.0V, Vin ≥ 0V,
Data retention current		_	_	8	μА	~+70°C	CS#≥Vcc-0.2V
		_	_	10	μА	~+85°C	
Chip deselect time to data retention	t <sub>CDR</sub>	0	_	_	ns	Soo roton	tion waveform
Operation recovery time	t <sub>R</sub>	5	_	_	ms	See retention waveform.	

Note 1. Typical parameter indicates the value for the center of distribution at 3.0V (Ta=25°C), and not 100% tested.

- 2. Typical parameter indicates the value for the center of distribution at 3.0V (Ta=40°C), and not 100% tested.
- 3. CS# controls address buffer, WE# buffer, OE# buffer and Din buffer. If data retention mode, Vin levels (address, WE#, OE#, I/O) can be in the high impedance state.

### **Low Vcc Data Retention Timing Waveforms**



Revision History	R1LP0408D Series Data Sheet

			Description						
Rev.	Date	Page	Page Summary						
1.00	2012.4.13	_	First Edition issued (SOP package)						
2.00	2012.5.30	P.1	Add TSOP package to Part Name Information						

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